

# AOZ8829ADI

4-Channel Ultra-Low Capacitance TVS Diode Array

## **General Description**

The AOZ8829ADI is a transient voltage suppressor array designed to protect high speed data lines such as HDMI 1.4/2.0, USB 3.0/3.1, LVDS, and V-by-one from damaging ESD events.

This device incorporates a numbers of surge rated, low capacitance steering diodes and a TVS in a single package. During transient conditions, the steering diodes direct the transient to either the positive side of the power supply line or to ground.

The AOZ8829ADI provides a typical line-to-line capacitance of 0.3 pF and low insertion loss providing greater signal integrity making it ideally suited for HDMI 1.4/2.0 or USB 3.0/3.1 applications, such as Digital TVs, DVD players, computing, set-top boxes and MDDI applications in mobile computing devices.

The AOZ8829ADI comes in a RoHS compliant and Halogen Free 2.5 mm x 1.0 mm x 0.55 mm DFN-10 package and is rated for -40°C to +125°C junction temperature range.

#### **Features**

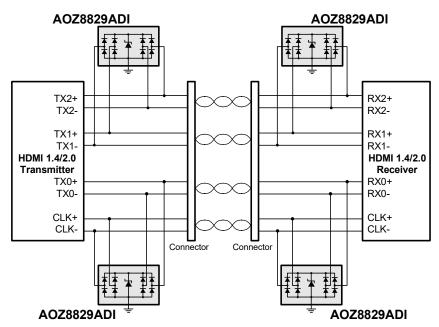
- IEC 61000-4-2 (ESD):
  - Air discharge: ±30 kV
  - Contact discharge: ±30 kV
- IEC 61000-4-5 (Lightning, 8/20 μs) 10 A
- Human Body Model (HBM) ±8 kV
- Protects four I/O lines
- Low capacitance between I/O lines: 0.3 pF
- Low clamping voltage
- Low operating voltage: 3.3, 5.0 V

## **Applications**

- HDMI 1.4/2.0, USB 3.0/3.1, Thunderbolt, V-by-One
- Monitors and flat panel displays
- Set-top box
- Video graphics cards
- Notebook computers



# **Typical Applications**





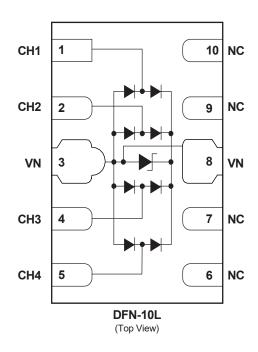
# **Ordering Information**

| Part Number   | Ambient Temperature Range | Package                       | Environmental |  |  |
|---------------|---------------------------|-------------------------------|---------------|--|--|
| AOZ8829ADI-03 | -40°C to +125°C           | 2.5 mm x 1.0 mm DFN-10L       | Green Product |  |  |
| AOZ8829ADI-05 | -40 C to +125 C           | 2.3 IIIII X 1.0 IIIII DFN-10L | Green roduct  |  |  |



AOS Green Products use reduced levels of Halogens, and are also RoHS compliant. Please visit <a href="https://www.aosmd.com/media/AOSGreenPolicy.pdf">www.aosmd.com/media/AOSGreenPolicy.pdf</a> for additional information.

# **Pin Configuration**



# **Absolute Maximum Ratings**

Exceeding the Absolute Maximum ratings may damage the device.

| Parameter  | Rating            |  |  |
|--|-------------------|--|--|
| Storage Temperature (T <sub>S</sub> )                | -65 °C to +150 °C |  |  |
| ESD Rating per IEC 61000-4-2, contact <sup>(1)</sup> | ±30 kV            |  |  |
| ESD Rating per IEC 61000-4-2, air <sup>(1)</sup>     | ±30 kV            |  |  |
| ESD Rating per Human Body Model <sup>(2)</sup>       | ±8 kV             |  |  |

#### Notes:

- 1. IEC 61000-4-2 discharge with C\_Discharge = 150pF, R\_Discharge = 330  $\Omega$ .
- 2. Human Body Discharge per MIL-STD-883, Method 3015 C  $_{\rm Discharge}$  = 100 pF, R  $_{\rm Discharge}$  = 1.5 k  $\Omega$ .

# **Maximum Operating Ratings**

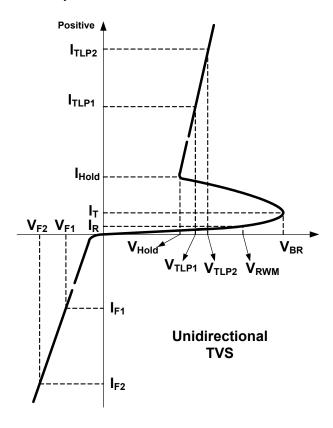
| Parameter                              | Rating            |
|--|-------------------|
| Junction Temperature (T <sub>J</sub> ) | -40 °C to +125 °C |

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## **Electrical Characteristics**

 $T_A$  = 25°C unless otherwise specified. Any I/O Pin-to-Ground.



## AOZ8829ADI-03

| Symbol           | Parameter   | Conditions   | Min. | Тур.        | Max       | Units  |
|------------------|---|--|------|-------------|-----------|--------|
| V <sub>RWM</sub> | Reverse Working Voltage   |  |      |             | 3.3       | V      |
| V <sub>BR</sub>  | Reverse Breakdown Voltage   | I <sub>T</sub> = 100 μA  | 5    |             |           | V      |
| I <sub>R</sub>   | Reverse Leakage Current   | Max. V <sub>RWM</sub>  |      | 1           | 50        | nA     |
| V <sub>F</sub>   | Forward Voltage   | I <sub>F</sub> = 15mA  |      | 0.85        |           | V      |
| V <sub>CL</sub>  | Clamping Voltage <sup>(1)(2)</sup><br>(100 ns Transmission Line<br>Pulse, I/O Pin to GND) | I <sub>TLP</sub> = 1 A<br>I <sub>TLP</sub> = -1 A                                    |      | 1.3<br>-1.3 | 2<br>-2   | V<br>V |
|                  |   | I <sub>TLP</sub> = 16 A<br>I <sub>TLP</sub> = -16 A                                  |      | 4.6<br>-4.2 | 6<br>-5.5 | V<br>V |
| R <sub>DNY</sub> | Dynamic Resistance <sup>(1)</sup>   | I <sub>TLP</sub> = 8A to 16 A  |      | 0.2         |           | Ω      |
| С                | Junction Capacitance  | V <sub>PIN 3,8</sub> = 0 V, V <sub>I/O</sub> = 1.65 V, f = 1 MHz                     |      | 0.55        | 0.69      | pF     |
|                  |   | V <sub>PIN 3,8</sub> = 0 V, V <sub>I/O</sub> = 0 V, f = 1 MHz,<br>I/O Pin-to-I/O Pin |      | 0.3         |           | pF     |

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## AOZ8829ADI-05

| Symbol           | Parameter   | Conditions   | Min. | Тур.        | Max       | Units  |
|------------------|---|--|------|-------------|-----------|--------|
| V <sub>RWM</sub> | Reverse Working Voltage   |  |      |             | 5         | V      |
| V <sub>BR</sub>  | Reverse Breakdown Voltage   | I <sub>T</sub> = 100 μA  | 6.5  |             |           | V      |
| I <sub>R</sub>   | Reverse Leakage Current   | Max. V <sub>RWM</sub>  |      | 1           | 50        | nA     |
| V <sub>F</sub>   | Forward Voltage   | I <sub>F</sub> = 15mA  |      | 0.85        |           | V      |
| V <sub>CL</sub>  | Clamping Voltage <sup>(1)(2)</sup><br>(100 ns Transmission Line<br>Pulse, I/O Pin to GND) | I <sub>TLP</sub> = 1 A<br>I <sub>TLP</sub> = -1 A                                    |      | 1.3<br>-1.3 | 2<br>-2   | V<br>V |
|                  |   | I <sub>TLP</sub> = 16 A<br>I <sub>TLP</sub> = -16 A                                  |      | 4.6<br>-4.2 | 6<br>-5.5 | V<br>V |
| R <sub>DNY</sub> | Dynamic Resistance <sup>(1)</sup>   | I <sub>TLP</sub> = 8A to 16 A  |      | 0.2         |           | Ω      |
| СЛ               | Junction Capacitance  | V <sub>PIN 3,8</sub> = 0 V, V <sub>I/O</sub> = 1.65 V, f = 1 MHz                     |      | 0.55        | 0.69      | pF     |
|                  |   | V <sub>PIN 3,8</sub> = 0 V, V <sub>I/O</sub> = 0 V, f = 1 MHz,<br>I/O Pin-to-I/O Pin |      | 0.3         |           | pF     |

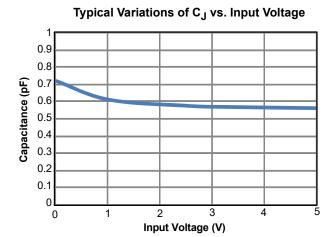
## Notes:

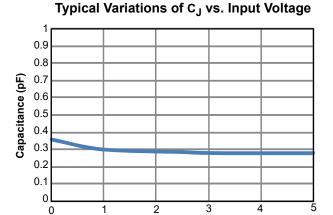
- 1. These specifications are guaranteed by design and characterization.
- $2.\ Measurements\ performed\ using\ a\ 100ns\ Transmission\ Line\ Pulse\ (TLP)\ system.$

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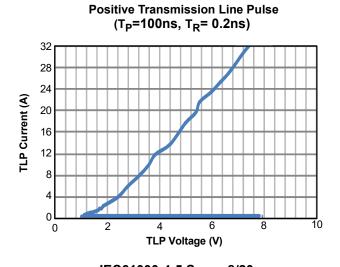


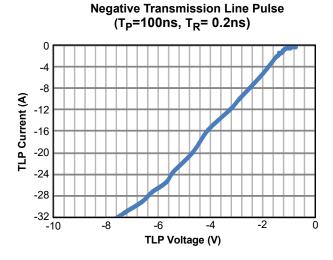
# **Typical Characteristics**

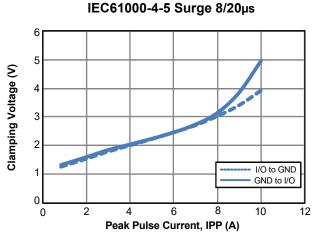




Input Voltage (V)









## **High Speed PCB Layout Guidelines**

Printed circuit board layout is the key to achieving the highest level of surge immunity on power and data lines. The location of the protection devices on the PCB is the simplest and most important design rule to follow. The AOZ8829ADI devices should be located as close as possible to the noise source. The AOZ8829ADI device should be placed on all data and power lines that enter or exit the PCB at the I/O connector. In most systems, surge pulses occur on data and power lines that enter the PCB through the I/O connector. Placing the AOZ8829ADI devices as close as possible to the noise source ensures that a surge voltage will be clamped before the pulse can be coupled into adjacent PCB traces.

In addition, the PCB should use the shortest possible traces. A short trace length equates to low impedance, which ensures that the surge energy will be dissipated by the AOZ8829ADI device. Long signal traces will act as antennas to receive energy from fields that are produced by the ESD pulse. By keeping line lengths as short as possible, the efficiency of the line to act as an antenna for ESD related fields is reduced. Minimize interconnecting line lengths by placing devices with the most interconnect as close together as possible. The protection circuits should shunt the surge voltage to either the reference or chassis ground. Shunting the surge voltage directly to the IC's signal ground can cause ground bounce. The clamping performance of TVS diodes on a single ground

PCB can be improved by minimizing the impedance with relatively short and wide ground traces. The PCB layout and IC package parasitic inductances can cause significant overshoot to the TVS's clamping voltage. The inductance of the PCB can be reduced by using short trace lengths and multiple layers with separate ground and power planes. One effective method to minimize loop problems is to incorporate a ground plane in the PCB design.

The AOZ8829ADI ultra-low capacitance TVS is designed to protect four high speed data transmission lines from transient over-voltages by clamping them to a fixed reference. The low inductance and construction minimizes voltage overshoot during high current surges. When the voltage on the protected line exceeds the reference voltage the internal steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. The AOZ8829ADI is designed for ease of PCB layout by allowing the traces to run underneath the device. The pinout of the AOZ8829ADI is designed to simply drop onto the IO lines of a High Definition Multimedia Interface (HDMI 1.4/2.0) or USB 3.0/3.1 design without having to divert the signal lines that may add more parasitic inductance. Pins 1, 2, 4 and 5 are connected to the internal TVS devices and pins 6, 7, 9 and 10 are no connects. The no connects was done so the package can be securely soldered onto the PCB surface.

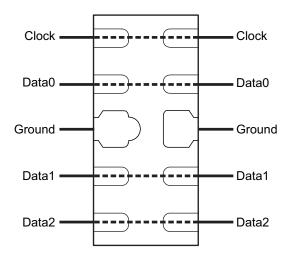


Figure 3. Flow Through Layout for HDMI 1.4/2.0

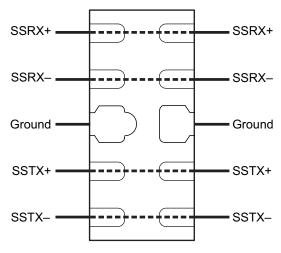


Figure 4. Flow Through Layout for USB 3.0/3.1

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